National Semiconductor

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LM133/LM333 3-Ampere Adjustable Negative Regulators

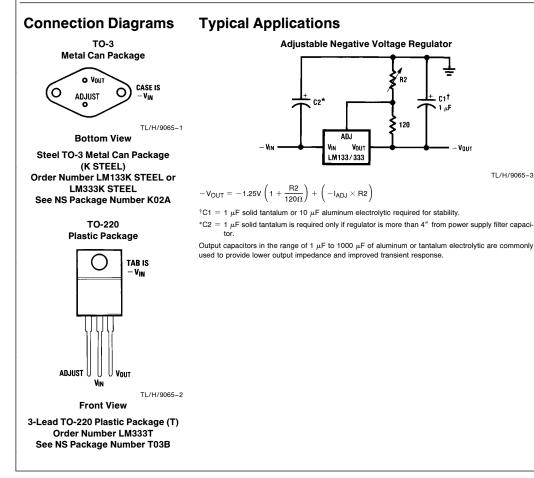
General Description

The LM133/LM333 are adjustable 3-terminal negative voltage regulators capable of supplying in excess of -3.0A over an output voltage range of -1.2V to -32V. These regulators are exceptionally easy to apply, requiring only 2 external resistors to set the output voltage and 1 output capacitor for frequency compensation. The circuit design has been optimized for excellent regulation and low thermal transients. Further, the LM133 series features internal current limiting, thermal shutdown and safe-area compensation, making them substantially immune to failure from overloads.

The LM133/LM333 serve a wide variety of applications including local on-card regulation, programmable-output voltage regulation or precision current regulation. The LM133/ LM333 are ideal complements to the LM150/LM350 adjustable positive regulators.

Features

- Output voltage adjustable from -1.2V to -32V
- 3.0A output current guaranteed, -55°C to +150°C
- Line regulation typically 0.01%/V
- Load regulation typically 0.2%
- Excellent rejection of thermal transients
- 50 ppm/°C temperature coefficient
- Temperature-independent current limit
- Internal thermal overload protection
- P⁺ Product Enhancement tested
- Standard 3-lead transistor package
- Output is short circuit protected



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LM133/LM333 3-Ampere Adjustable Negative Regulators

Absolute Maximum Ra	tings (Note 1)			
If Military/Aerospace specified de please contact the National Se	• •	Storage Temperature	-65°C to +150°C	
Office/Distributors for availability and specifications.		Lead Temperature (Soldering, 10 sec.) TO-3 Package	300°C	
Power Dissipation	Internally Limited	TO-220 Package	260°C	
Input-Output Voltage Differential	35V	ESD Susceptibility	TBD	
Operating Junction Temperature Rang LM133 LM333	e T _{MIN} to T _{MAX} -55°C to +150°C -40°C to +125°C			

Electrical Characteristics LM133 Specifications with standard typeface are for $T_J = 25^{\circ}$ C, and those with
boldface type apply over the full operating temperature range. (Note 3)

Parameter	Conditions	Typical	Min (Note 2)	Max (Note 2)	Units
Reference Voltage	$I_L = 10 \text{ mA}$	-1.250	-1.238	-1.262	v
	$\begin{array}{l} 3V \leq \left V_{IN} - V_{OUT}\right \leq 35V \\ 10 \text{ mA} \leq I_L \leq 3A, P \leq P_{MAX} \end{array}$	- 1.250	- 1.225	- 1.275	v
Line Regulation	$\begin{array}{l} 3V \leq \left V_{IN} - V_{OUT}\right \leq 35V \\ I_{OUT} = 50 \text{ mA (Note 4)} \end{array}$	0.01 0.02		0.02 0.05	% /V
Load Regulation	10 mA \leq I_{OUT} \leq 3A, P \leq P_{MAX} (Notes 4, 5)	0.2 0.4		0.5 1.0	%
Thermal Regulation	10 ms Pulse	0.002		0.01	% /W
Temperature Stability	$T_{MIN} \leq T_J \leq T_{MAX}$	0.4			%
Long Term Stability	$T_{J} = 125^{\circ}C$, 1000 Hours	0.15			%
Adjust Pin Current		65 70		90 100	μΑ
Adjust Pin Current Change	$\begin{array}{l} 10 \text{ mA} \leq I_L \leq 3\text{A} \\ 3.0\text{V} \leq \left \text{V}_{\text{IN}} - \text{V}_{\text{OUT}}\right \leq 35\text{V} \end{array}$	2		6	μΑ
Minimum Load Current	$ V_{IN} - V_{OUT} \le 35V$	2.5		5.0	- mA
	$ V_{\text{IN}} - V_{\text{OUT}} \leq 10V$	1.2		2.5	
Current Limit (Note 5)	$3V \leq \left V_{\text{IN}} - V_{\text{OUT}}\right \leq 10V$	3.9	3.0		
	$ V_{IN} - V_{OUT} = 20V$	2.4	1.25		A
	$ V_{IN} - V_{OUT} = 30V$	0.4	0.3		
Output Noise (% of V _{OUT})	10 Hz to 10 kHz	0.003			% (rms
Ripple Rejection	$\label{eq:VOUT} \begin{array}{l} V_{OUT}=10V, f=120 \ Hz \\ C_{ADJ}= 0 \ \mu F \\ C_{ADJ}=10 \ \mu F \end{array}$	60 77			dB
Thermal Resistance Junction-to-Case	TO-3 Package (K STEEL)	1.2		1.8	°C/W
Thermal Shutdown Temperature		163	150	190	°C

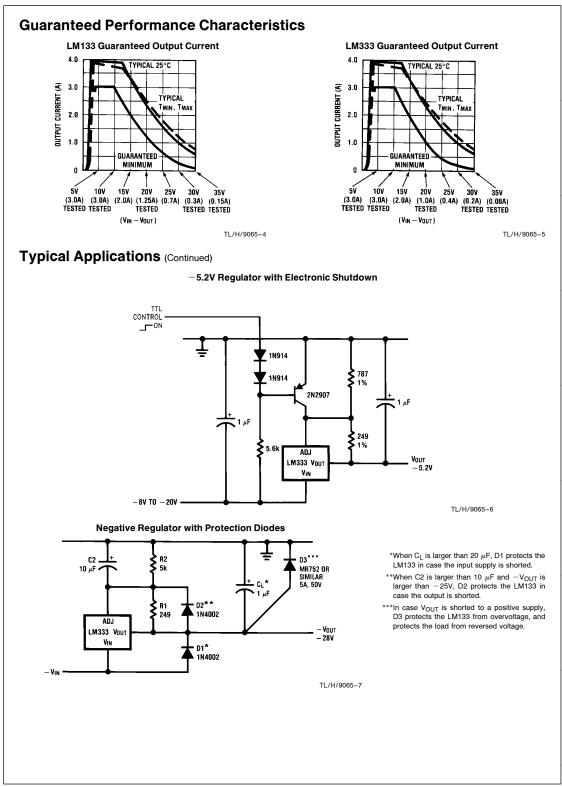
Parameter	Conditions	Typical	Min (Note 2)	Max (Note 2)	Units
Reference Voltage	$I_L = 10 \text{ mA}$	-1.250	-1.225	-1.275	v
	$\begin{array}{l} 3V \leq \left V_{IN} - V_{OUT}\right \leq 35V \\ 10 \text{ mA} \leq I_L \leq 3A, P \leq P_{MAX} \end{array}$	- 1.250	- 1.213	- 1.287	
Line Regulation	$\begin{array}{l} 3V \leq V_{IN} - V_{OUT} \leq 35V \\ I_{OUT} = 50 \text{ mA (Note 4)} \end{array}$	0.01 0.02		0.04 0.07	% /V
Load Regulation	10 mA \leq IL \leq 3A, P \leq P_MAX (Notes 4 and 5)	0.2 0.4		1.0 1.5	%
Thermal Regulation	10 ms Pulse	0.002		0.02	% /W
Temperature Stability	$T_{MIN} \leq T_J \leq T_{MAX}$	0.5			%
Long Term Stability	$T_{J} = 125^{\circ}C$, 1000 Hours	0.2			%
Adjust Pin Current		65 70		95 100	μΑ
Adjust Pin Current Change	$\begin{array}{l} 10 \text{ mA} \leq \text{I}_{\text{L}} \leq 3\text{A} \\ 3.0\text{V} \leq \left \text{V}_{\text{IN}} - \text{V}_{\text{OUT}}\right \leq 35\text{V} \end{array}$	2.5		8	μΑ
Minimum Load	$ V_{\text{IN}} - V_{\text{OUT}} \le 35V$	2.5		10	- mA
Current	$\left V_{\text{IN}}-V_{\text{OUT}}\right \leq 10V$	1.5		5.0	
Current Limit	$3V \leq \left V_{IN} - V_{OUT}\right \leq 10V$	3.9	3.0		A
(Note 5)	$ V_{IN} - V_{OUT} = 20V$	2.4	1.0		
	$ V_{IN} - V_{OUT} = 30V$	0.4	0.20		
Output Noise (% of V _{OUT})	10 Hz to 10 kHz	0.003			% (rms
Ripple Rejection	$\label{eq:VOUT} \begin{array}{l} V_{OUT} = 10V, f = 120 \; Hz \\ C_{ADJ} = \; 0 \; \muF \\ C_{ADJ} = \; 10 \; \muF \end{array}$	60 77			dB
Thermal Resistance Junction to Case	TO-3 Package (K STEEL)	1.2		1.8	•C/W
	TO-220 Package (T)	3		4	
Thermal Shutdown Temperature		163			°C
Thermal Resistance	K Package	35			°C/W
Junction to Ambient (No Heatsink)	T Package	50			

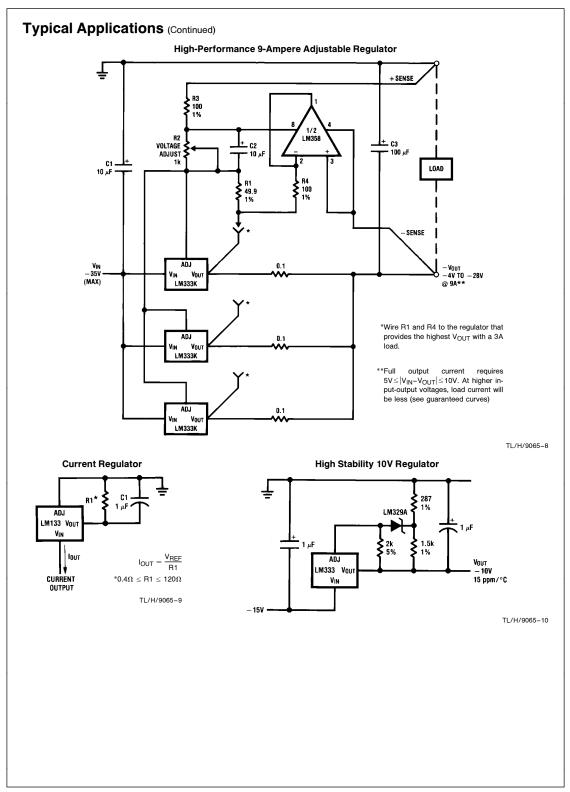
Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device outside of its stated operating conditions.

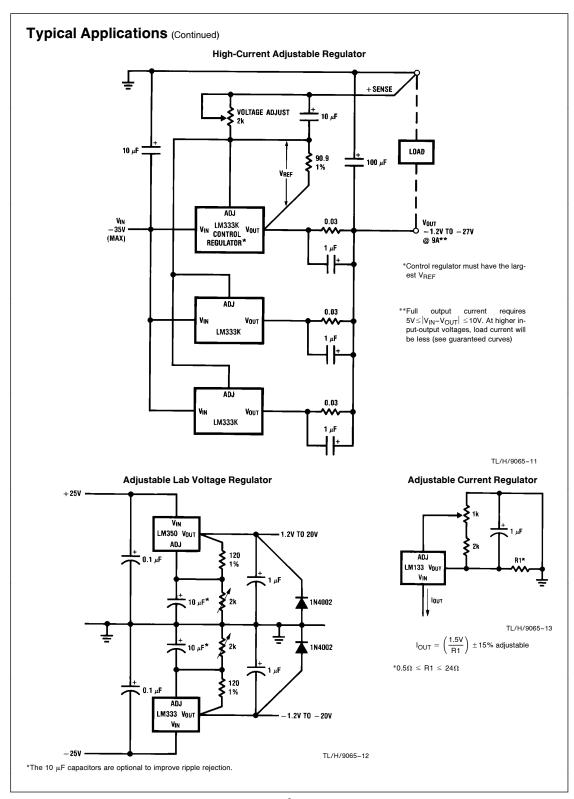
Note 2: All limits are guaranteed at either room temperature (standard type face) or at temperature extremes (bold typeface) by production testing or correlation techniques using standard Statistical Quality Control (SQC) methods.

Note 3: Unless otherwise specified: $|V_{IN}$ - $V_{OUT}|$ = 5V, I_{OUT} = 0.5A, P_{DISS} \leq 30W.

Note 4: Load and line regulation are measured at constant junction temperature, using low duty cycle pulse testing (output voltage changes due to heating effects are covered by the Thermal Regulation specification). For the TO-3 package, load regulation is measured on the output pin, $\frac{1}{6}$ " below the base of the package. Note 5: The output current of the LM333 is guaranteed to be \geq 3A in the range $3V \leq |V_{IN} - V_{OUT}| \leq 10V$. For the range $10V \leq |V_{IN} - V_{OUT}| \leq 15V$, the guaranteed minimum output current is equal to: $30/(V_{IN} - V_{OUT})$. Refer to graphs for guaranteed output currents at other voltages.



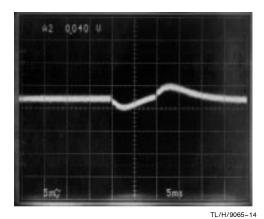




Typical Applications (Continued)

THERMAL REGULATION

When power is dissipated in an IC, a temperature gradient occurs across the IC chip affecting the individual IC circuit components. With an IC regulator, this gradient can be especially severe since the power dissipation is large. Thermal regulation is the effect of these temperature gradients on output voltage (in percentage output change) per watt of power change in a specified time. Thermal regulation error is independent of electrical regulation or temperature coefficient, and occurs within 5 ms to 50 ms after a change in power dissipation. Thermal regulation depends on IC layout as well as electrical design. The thermal regulation of a voltage regulator is defined as the percentage change of V_{OUT}.



per watt, within the first 10 ms after a step of power is applied. The LM133's specification is 0.01%/W, max.

In *Figure 1*, a typical LM133's output drifts only 2 mV (or 0.02% of V_{OUT} = -10V) when a 20W pulse is applied for 10 ms. This performance is thus well inside the specification limit of 0.01%/W×20W = 0.2% max. When the 20W pulse is ended, the thermal regulation again shows a 2 mV step as the LM133 chip cools off. Note that the load regulation error of about 1 mV (0.01%) is additional to the thermal regulation error. In *Figure 2*, when the 20W pulse is applied for 100 ms, the output drifts only slightly beyond the drift in the first 10 ms, and the thermal error stays well within 0.1% (10 mV).

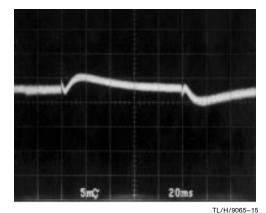
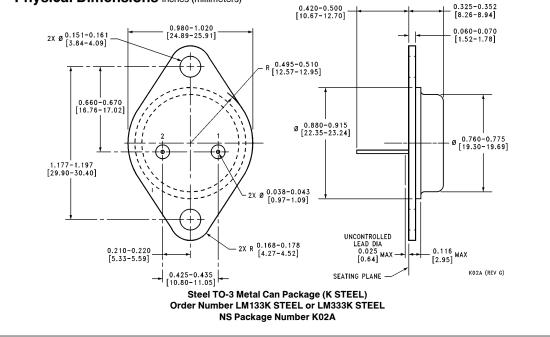
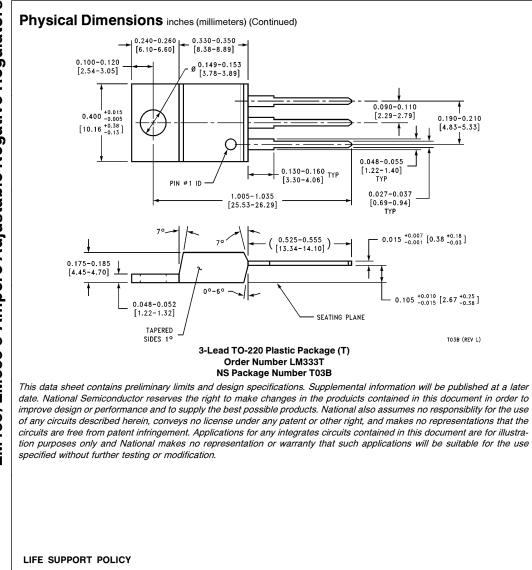


FIGURE 1

Physical Dimensions inches (millimeters)

FIGURE 2





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